

Nips Thyristor Modules/Water Cooling MD1000T**W MR1000T**W MC1000T**W

Features :

- Isolated mounting base 2500V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications :

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

V_{DSM}, V_{RSM}	V_{DRM}, V_{RRM}	品名
900V	800V	Mx1000T80W
1100V	1000V	Mx1000T100W
1300V	1200V	Mx1000T120W
1500V	1400V	Mx1000T140W
1700V	1600V	Mx1000T160W
1900V	1800V	Mx1000T180W

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_J(^{\circ}C)$	VALUE			UNIT
				Min.	Typ.	Max.	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Single side cooled, $T_c=55^{\circ}C$	125			1000	A
$I_{T(RMS)}$	RMS on-state current					1570	A
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	tp=10ms	125	800		1800	V
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			55	mA
I_{TSM}	Surge on-state current	10ms half sine wave, $V_R=0.6V_{RRM}$	125			26.0	kA
I^2t	I^2t for fusing coordination					3380	$A^2s \times 10^3$
V_{TO}	Threshold voltage		125			0.81	V
r_T	On-state slope resistance					0.21	$m\Omega$
V_{TM}	Peak on-state voltage			25		2.0	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM}$	125			800	$V/\mu s$
di/dt	Critical rate of rise of on-state current	Gate source 1.5A $t \leq 0.5\mu s$ Repetitive	125			100	$A/\mu s$
I_{GT}	Gate trigger current	$V_A=12V, I_A=1A$	25	30		200	mA
V_{GT}	Gate trigger voltage			1.0		3.0	V
I_H	Holding current			20		200	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.2			V
I_{GD}	Non-trigger gate current	$V_{DM}=67\%V_{DRM}$	125	1.5			mA
$R_{th(j-c)}$	Thermal resistance Junction to case	D.C. Single side cooled, per chip. DC				0.052	$^{\circ}C/W$
$R_{th(c-w)}$	Thermal resistance case to water	D.C. Single side cooled, per chip. (6L/min)				0.037	$^{\circ}C/W$
V_{iso}	Isolation voltage	50Hz,R.M.S,t=1min, $I_{iso}:1mA(MAX)$		2500			V
F_m	Terminal connection torque(M12)			12.0		16.0	$N \cdot m$
	Mounting torque(M8)			10.0		12.0	$N \cdot m$
T_{vj}	Junction temperature			-40		125	$^{\circ}C$
T_{stg}	Stored temperature			-40		125	$^{\circ}C$
T_{water}	Water temperature	Water flow=6L/min		-		30	$^{\circ}C$
-	Water Pressure loss				41		kPa
W_t	Weight				3220		g
Outline		M15					

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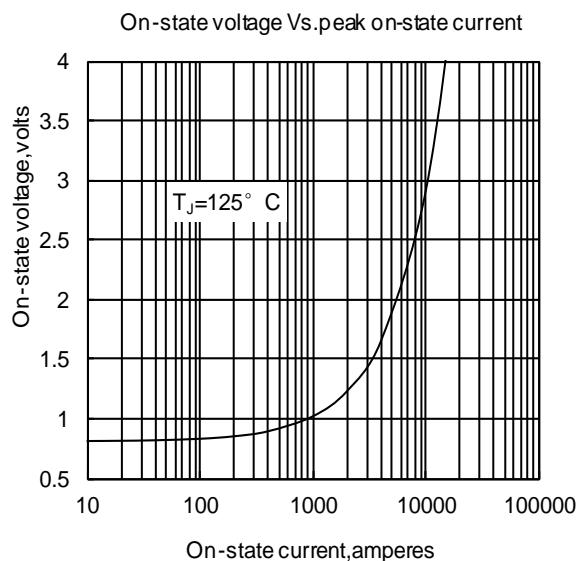


Fig1

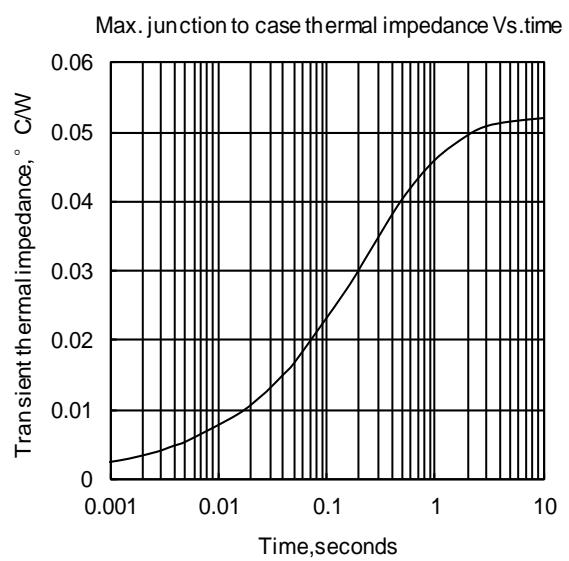


Fig2

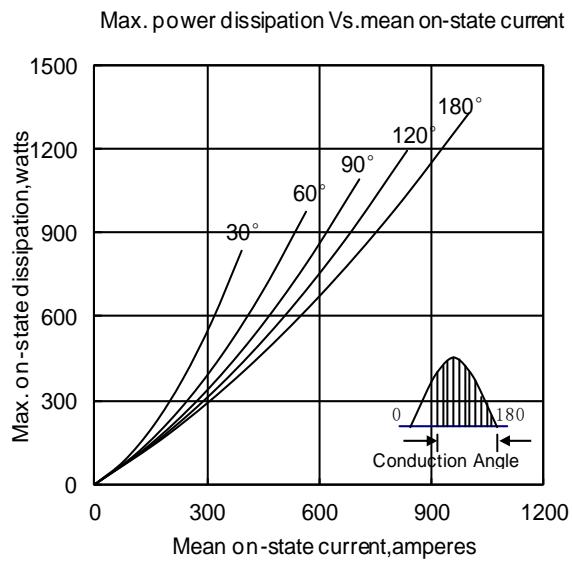


Fig3

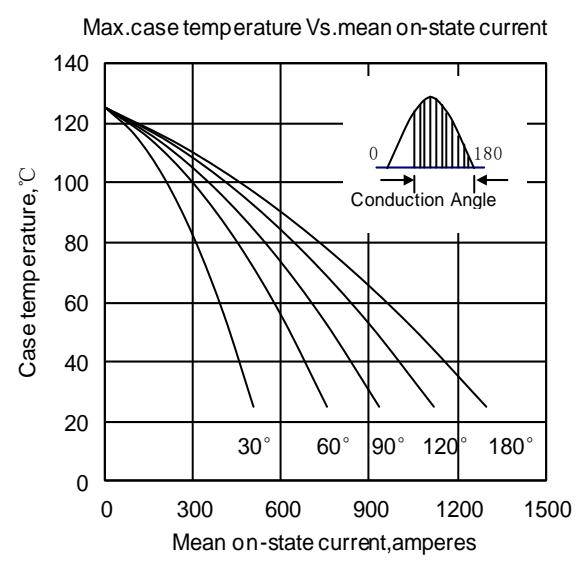


Fig4

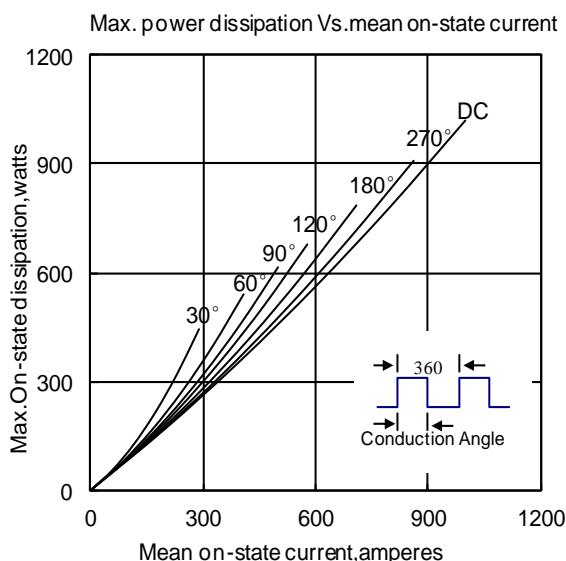


Fig5

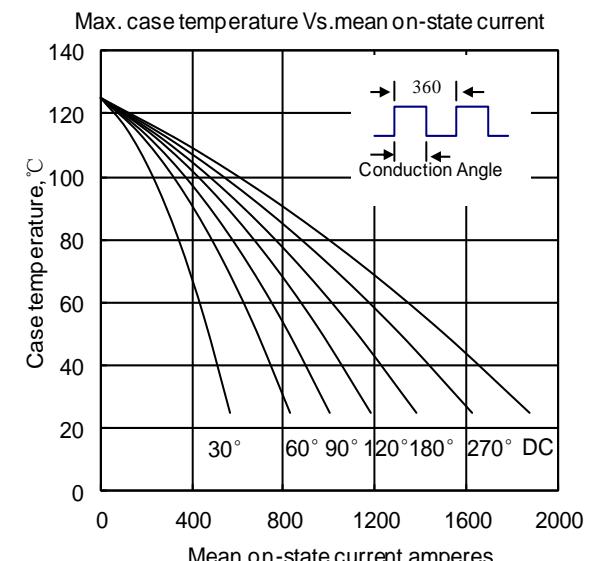


Fig6

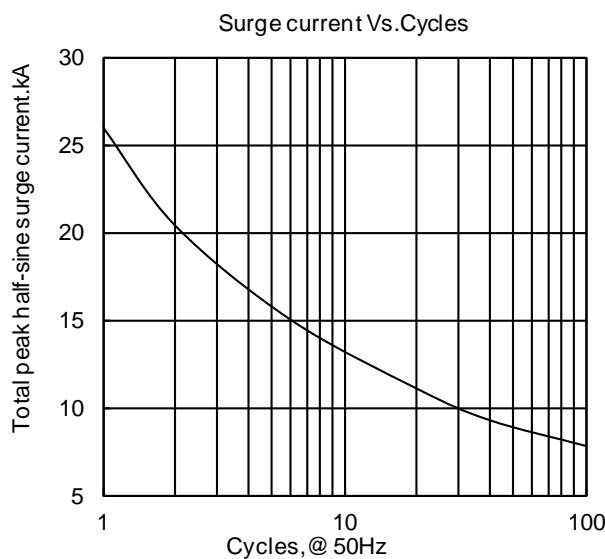


Fig7

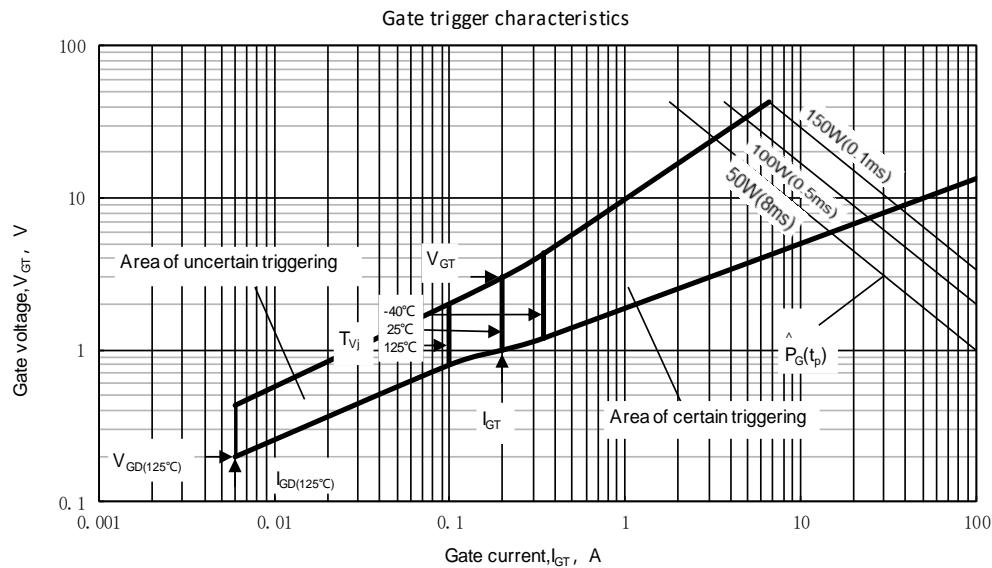


Fig8

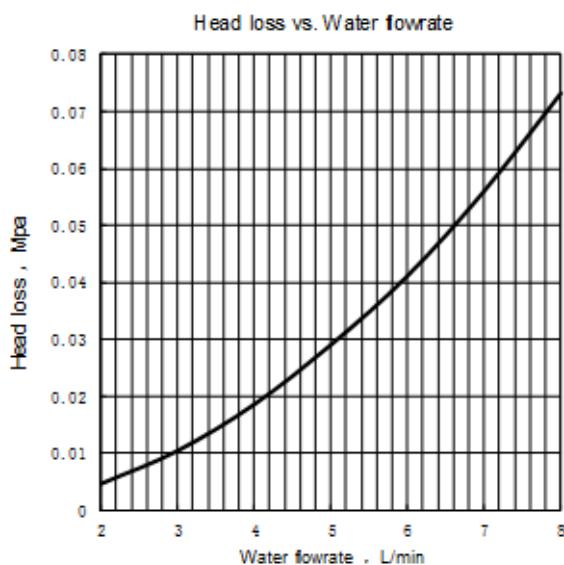


Fig9

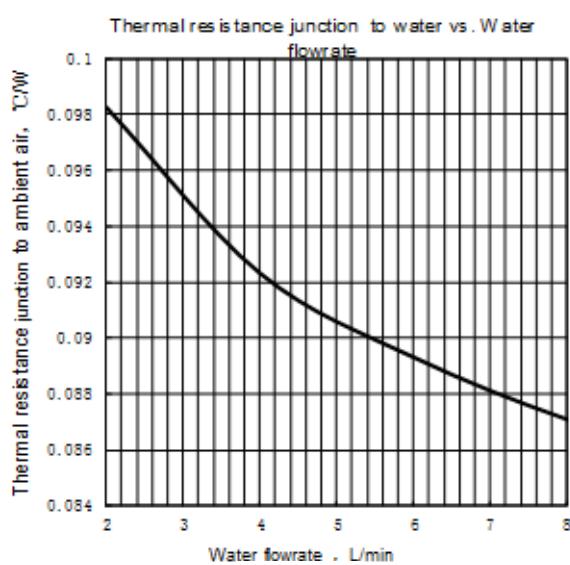
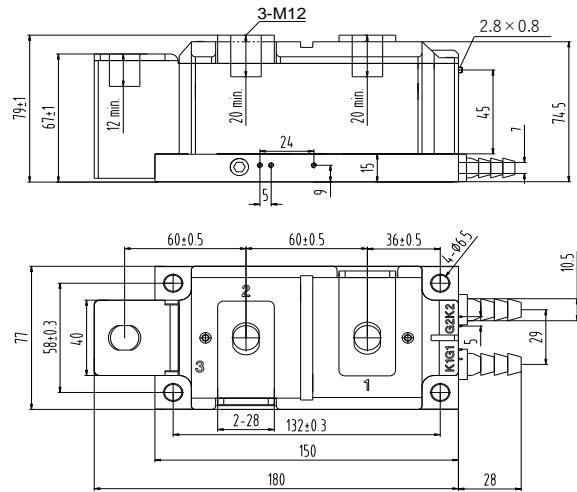


Fig. 10

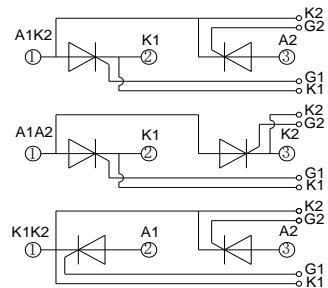
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Unmarked dimensional tolerance : $\pm 0.5\text{mm}$